



INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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First Named Inventor

KAMIYAMA

Group Art Unit

2814

Examiner Name

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Attorney Docket Number

403018

**Examiner
Initials**

Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number (s), publisher, city and/or country where published.

Translation

Yes

 No^{*+}

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HOBBS, C. et al.; "Fermi Level Pinning at the PolySi/Metal Oxide Interface", 2003 Symposium of VLSI Tech. Digest of Technical Papers, pp. 3-4.

**Examiner
Signature**

Long Pham

Date Considered

7/24/06

* A concise statement of relevance is being submitted in lieu of a translation. 37 CFR 1.98(a)(3).